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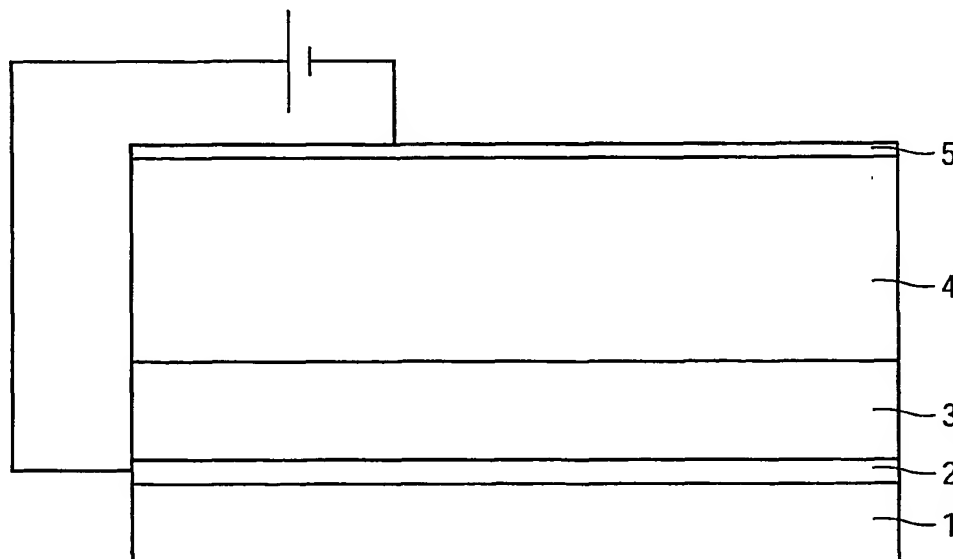
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(54) Title: LIGHT-EMITTING DIODE



(57) Abstract: The invention pertains to a light-emitting diode (LED) comprising layers of an anode, an acidic hole conducting-injecting material, a light-emitting polymer, and a cathode, characterized in that the hole conducting-injecting material comprises a poly(3,4-ethylenedioxythiophene poly(styrenesulfonate) (PEDOT), which is obtainable by at least partially neutralizing the PEDOT with an anion that is comprised or formed from a sodium or potassium compound, and the light-emitting material comprises a light-emitting p-arylenevinylene polymer (PAV). The invention further relates to a method for increasing the efficiency of said light-emitting diode.



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